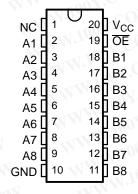
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FEATURES

- Standard '245-Type Pinout
- Output Voltage Translation Tracks V_{CC}
- Supports Mixed-Mode Signal Operation on All Data I/O Ports
 - 5-V Input Down to 3.3-V Output Level Shift With 3.3-V V_{CC}
 - 5-V/3.3-V Input Down to 2.5-V Output Level
 Shift With 2.5-V V_{CC}
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Bidirectional Data Flow With Near-Zero Propagation Delay
- Low ON-State Resistance (r_{on}) Characteristics ($r_{on} = 5 \Omega \text{ Typ}$)
- Low Input/Output Capacitance Minimizes Loading (C_{io(OFF)} = 5 pF Typ)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I_{CC} = 40 μA Max)

- V_{CC} Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I_{off} Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA
 Per JESD 17
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, PCI Interface, USB Interface, Memory Interleaving, Bus Isolation
- Ideal for Low-Power Portable Equipment

DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)



NC - No internal connection

DESCRIPTION/ORDERING INFORMATION

The SN74CB3T3245 is a high-speed TTL-compatible FET bus switch with low ON-state resistance (r_{on}), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V_{CC} . The SN74CB3T3245 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).

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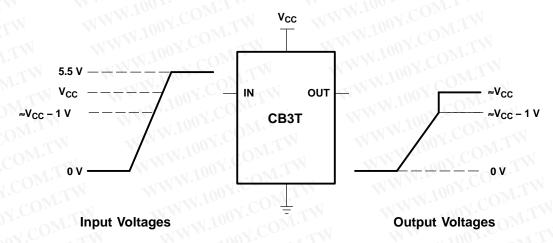


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



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DESCRIPTION/ORDERING INFORMATION (CONTINUED)



NOTE A: If the input high-voltage (V_{IH}) level is greater than or equal to (V_{CC} – 1 V) and less than or equal to 5.5 V, then the output high-voltage (V_{OH}) level will be equal to approximately the V_{CC} voltage level.

Figure 1. Typical DC Voltage Translation Characteristics

The SN74CB3T3245 is an 8-bit bus switch with a single ouput-enable (\overline{OE}) input and a standard '245 pinout. When \overline{OE} is low, the 8-bit bus switch is ON, and the A port is connected to the B port, allowing bidirectional data flow between ports. When \overline{OE} is high, the 8-bit bus switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

To ensure the high-impedance state during power up or power down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

ORDERING INFORMATION

TA	PACKAG	iE ⁽¹⁾	ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube	SN74CB3T3245DW	CD2T224F
	SOIC - DW	Tape and reel	SN74CB3T3245DWR	CB3T3245
–40°C to 85°C	SSOP (QSOP) - DBQ	Tape and reel	SN74CB3T3245DBQR	CB3T3245
-40°C 10 85°C	TCCOD DW	Tube	SN74CB3T3245PW	VC245
	TSSOP – PW	Tape and reel	SN74CB3T3245PWR	KS245
	TVSOP - DGV	Tape and reel	SN74CB3T3245DGVR	KS245

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

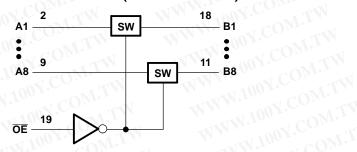
INPUT OE	INPUT/OUTPUT A	FUNCTION
LVIV	СОВ	A port = B port
H. 10	Z	Disconnect



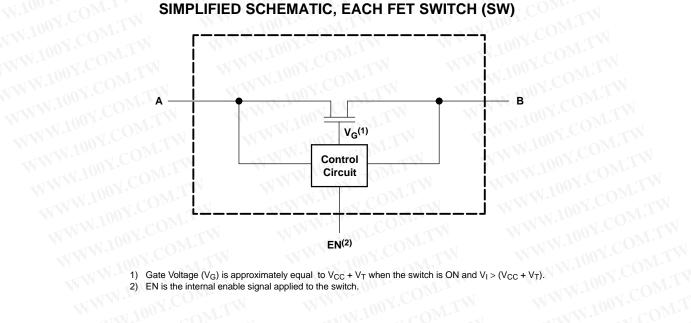
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LOGIC DIAGRAM (POSITIVE LOGIC)



SIMPLIFIED SCHEMATIC, EACH FET SWITCH (SW)



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SN74CB3T3245 8-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE WITH 5-V-TOLERANT LEVEL SHIFTER



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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range ⁽²⁾	CIW WWW 100X.	-0.5	7	V
V _{IN}	Control input voltage range ⁽²⁾⁽³⁾	WWW.	-0.5	7	V
V _{I/O}	Switch I/O voltage range ⁽²⁾⁽³⁾⁽⁴⁾	W. I	-0.5	7	V
I _{IK}	Control input clamp current	V _{IN} < 0	COWIT	-50	mA
I _{I/OK}	I/O port clamp current	V _{I/O} < 0	OY. COM.TW	-50	mA
I _{I/O}	ON-state switch current ⁽⁵⁾	COMP.	ON COM	√ ±128	mA
1.100	Continuous current through V _{CC} or GND	COM.	COM	±100	mA
100	N. TW WW 100x	DBQ package	100 r. COM:	68	
0	Package thermal impedance ⁽⁶⁾	DGV package	1007.001	92	°C/W
θ_{JA}	Package thermal impedance(*)	DW package	N. COn	58	-0/00
		PW package	M.Ing CON	83	
T _{stg}	Storage temperature range	OO Y. WITH	-65	150	°C

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to ground unless otherwise specified.

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 V_{I} and V_{O} are used to denote specific conditions for $V_{I/O}$.

I_I and I_O are used to denote specific conditions for I_{I/O}.

Recommended Operating Conditions⁽¹⁾

110001	mmended Operating Conditions	M. 1001. COWITA	MIN	MAX	UNIT
V _{CC}	Supply voltage	M. 100 F. COMP.	2.3	3.6	V
	High-level control input voltage	V _{CC} = 2.3 V to 2.7 V	1.7	5.5	
V _{IH}		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2	5.5	V
	Land William CO	V _{CC} = 2.3 V to 2.7 V	0	0.7	CO
V_{IL}	Low-level control input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	0.8	< CO
V _{I/O}	Data input/output voltage	M. 1003. COM.I	0	5.5	V
T _A	Operating free-air temperature	MAN TODA CO	-40	85	°C

All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

The package thermal impedance is calculated in accordance with JESD 51-7.



SN74CB3T3245 8-BIT FET BUS SWITCH 2.5-V/3.3-V LOW-VOLTAGE WITH 5-V-TOLERANT LEVEL SHIFTER

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Electrical Characteristics(1)

over recommended operating free-air temperature range (unless otherwise noted)

P/	RAMETER	TEST CONDITION	ONS	MIN	TYP ⁽²⁾	MAX	UNIT	
V _{IK}	WT	$V_{CC} = 3 \text{ V, I}_{I} = -18 \text{ mA}$	TI		-1.2	V		
V _{OH}	See Figure 3 and Figure 4				W			
I _{IN}	Control inputs	V _{CC} = 3.6 V, V _{IN} = 3.6 V to 5.5 V or GND	TWW.In	0_{Mr} ,	-XX	±10	μΑ	
UO X.C.	WILI	M. 1001.	$V_I = V_{CC} - 0.7 \text{ V to } 5.5 \text{ V}$	Mo	1.	±20		
li C		$V_{CC} = 3.6 \text{ V}$, Switch ON, $V_{IN} = V_{CC}$ or GND	$V_{I} = 0.7 \text{ V to } V_{CC} - 0.7 \text{ V}$		TW	-40	μΑ	
		MANN TO COM.	$V_1 = 0 \text{ to } 0.7 \text{ V}$	Cor	W	±5		
I _{OZ} (3)	OWITH	$V_{CC} = 3.6 \text{ V}, V_{O} = 0 \text{ to } 5.5 \text{ V}, V_{I} = 0, \text{ Switch}$	OFF, V _{IN} = V _{CC} or GND	1 CO	Mr.	±10	μΑ	
I _{off}	Y.C. TI	$V_{CC} = 0$, $V_{O} = 0$ to 5.5 V, $V_{I} = 0$,	W W 100	1.	M_{JA}	10	μΑ	
Icc		$V_{CC} = 3.6 \text{ V}, I_{I/O} = 0,$	$V_1 = V_{CC}$ or GND	M.C.	TIME	40	^	
		Switch ON or OFF, $V_{IN} = V_{CC}$ or GND	V _I = 5.5 V	ON COM		40	μΑ	
$\Delta I_{CC}^{(4)}$	Control inputs	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$, One input at $V_{CC} - 0.6 \text{ V}$	$V_{CC} = 3 \text{ V}$ to 3.6 V, One input at $V_{CC} - 0.6 \text{ V}$, Other inputs at V_{CC} or GND		COM.	300	μΑ	
C _{in}	Control inputs	$V_{CC} = 3.3 \text{ V}, V_{IN} = V_{CC} \text{ or GND}$	V.I.M. M.	100,3	4	TA	pF	
C _{io(OFF)}	COM.	$V_{CC} = 3.3 \text{ V}$, $V_{I/O} = 5.5 \text{ V}$, 3.3 V , or GND, Switch OFF, $V_{IN} = V_{CC}$ or GND			5	TI	pF	
	Too COM	V 22 V Cuitab ON V V 27 CND	V _{I/O} = 5.5 V or 3.3 V	1.5	C 5		N	
C _{io(ON)}	$V_{CC} = 3.3 \text{ V, Switch ON, } V_{IN} = V_{CC} \text{ o}$		V _{I/O} = GND	13)		Mer	pF	
WW	100X.C	V 22V TVD + V 25V V 2	I _O = 24 mA	-xxi 10	5	8.5		
- (5)		$V_{CC} = 2.3 \text{ V}, \text{ TYP at } V_{CC} = 2.5 \text{ V}, V_{I} = 0$	I _O = 16 mA	144	5 5	8.5		
r _{on} (5)		V 2VV 0	I _O = 64 mA	WW.	5	7	Ω	
		$V_{CC} = 3 \text{ V}, V_{I} = 0$	I _O = 32 mA		.100 5	~ 7		

- V_{IN} and I_{IN} refer to control inputs. V_{I} , V_{O} , I_{I} , and I_{O} refer to data pins. All typical values are at V_{CC} = 3.3 V (unless otherwise noted), T_{A} = 25°C.
- For I/O ports, the parameter I_{OZ} includes the input leakage current.
- This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V_{CC} or GND.
- Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.

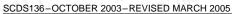
Switching Characteristics

over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	TO	V _{CC} = 1 ± 0.2	2.5 V 2 V	V _{CC} = 3 ± 0.3	3.3 V 3 V	UNIT
WWW.	(INPUT)	(OUTPUT)	MIN	MAX	MIN	MAX	
t _{pd} ⁽¹⁾	A or B	B or A	Ober	0.15	W	0.25	ns
t _{en}	OE OE	A or B	CO M. 1	10.5	1	8	ns
t _{dis}	<u>OE</u>	A or B	1.1	5.5	1	7.5	ns

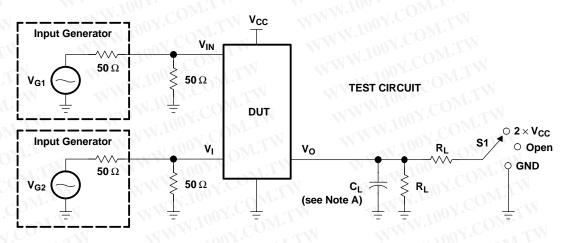
The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

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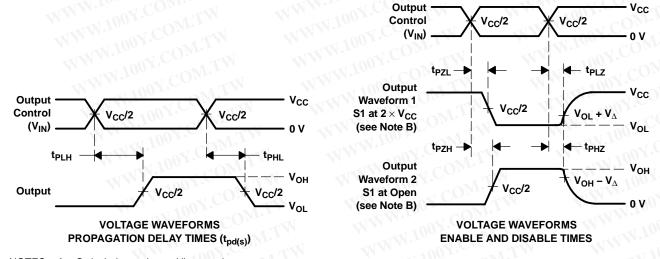




PARAMETER MEASUREMENT INFORMATION



TEST	V _{CC}	S1	RL	V _I	CL	V_{Δ}
t _{pd(s)}	2.5 V ± 0.2 V	Open	500 Ω	3.6 V or GND	30 pF	700
-pu(s)	3.3 V \pm 0.3 V	Open	500 Ω	5.5 V or GND	50 pF	100
t _{PLZ} /t _{PZL}	2.5 V ± 0.2 V	2×V _{CC}	500 Ω	GND	30 pF	0.15 V
tPLZ/tPZL	3.3 V \pm 0.3 V	2×V _{CC}	500 Ω	GND	50 pF	0.3 V
t _{PHZ} /t _{PZH}	2.5 V ± 0.2 V	Open	500 Ω	3.6 V	30 pF	0.15 V
'PHZ' 'PZH	3.3 V \pm 0.3 V	Open	500 Ω	5.5 V	50 pF	0.3 V



NOTES: A. C_L includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \Omega$, $t_f \leq$ 2.5 ns, $t_f \leq$ 2.5 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PLH} and t_{PHL} are the same as t_{pd(s)}. The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.

Figure 2. Test Circuit and Voltage Waveforms



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TYPICAL CHARACTERISTICS

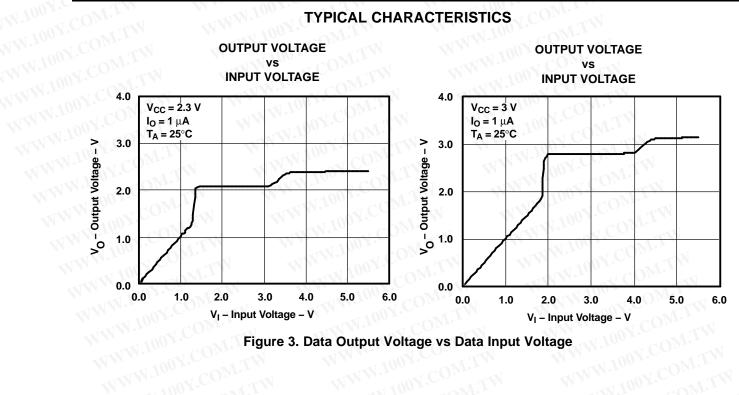
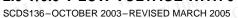


Figure 3. Data Output Voltage vs Data Input Voltage WWW.100Y.COM.TW

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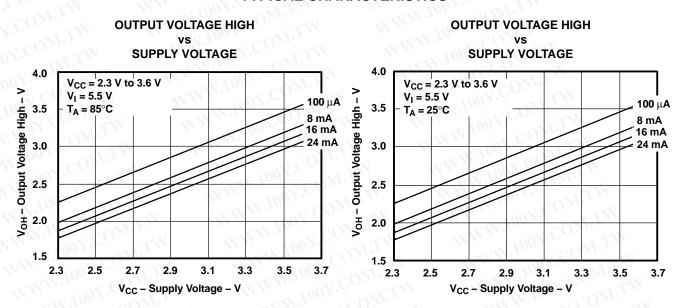
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TYPICAL CHARACTERISTICS



OUTPUT VOLTAGE HIGH VS

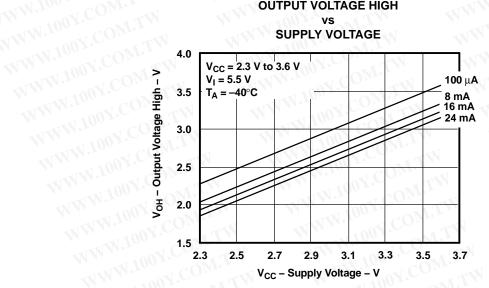


Figure 4. V_{OH} Values

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PACKAGE OPTION ADDENDUM



24-May-2007

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp (3)
74CB3T3245DBQRE4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
74CB3T3245DBQRG4	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
74CB3T3245DGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74CB3T3245DGVRG4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DBQR	ACTIVE	SSOP/ QSOP	DBQ	20	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74CB3T3245DGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWG4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWR	ACTIVE	TSSOP	PW 🕥	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74CB3T3245PWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

PACKAGE OPTION ADDENDUM



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package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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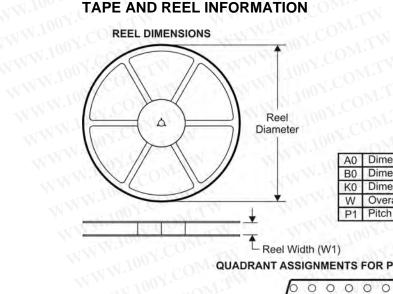
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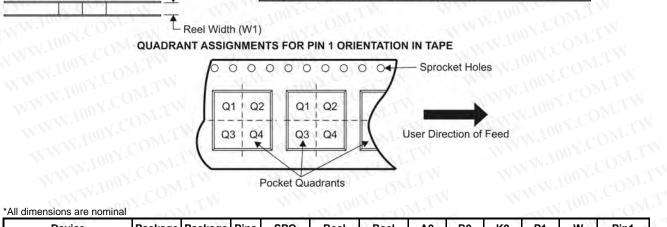
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TAPE AND REEL INFORMATION



TAPE DIMENSIONS ← K0 ← P1→ Φ 0 0 0 0 0 0 0 0 0 0 → A0 ← Cavity

A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
D1	Pitch between successive cavity centers



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Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74CB3T3245DBQR	SSOP/ QSOP	DBQ	20	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74CB3T3245DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74CB3T3245DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1
SN74CB3T3245PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1

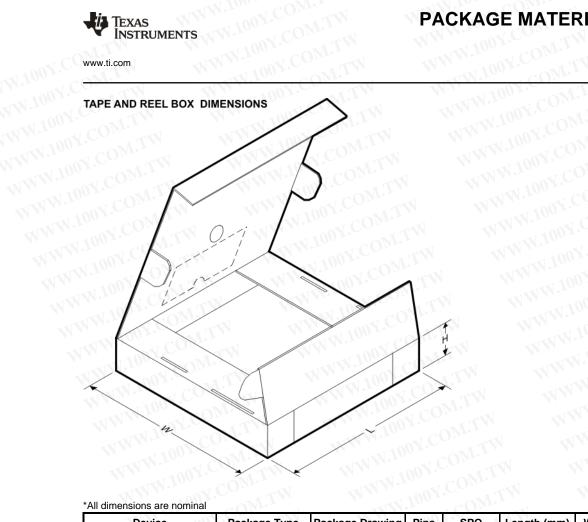
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Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74CB3T3245DBQR	SSOP/QSOP	DBQ	20	2500	346.0	346.0	33.0
SN74CB3T3245DGVR	TVSOP	DGV	20	2000	346.0	346.0	29.0
SN74CB3T3245DWR	SOIC	DW	20	2000	346.0	346.0	41.0
SN74CB3T3245PWR	TSSOP	PW	20	2000	346.0	346.0	33.0

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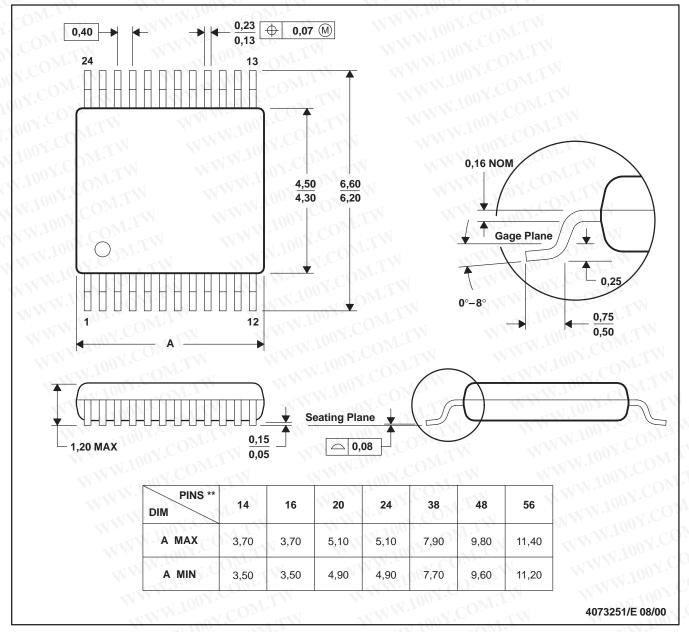
Http://www. 100y. com. tw

COM.TW

DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153

14/16/20/56 Pins - MO-194

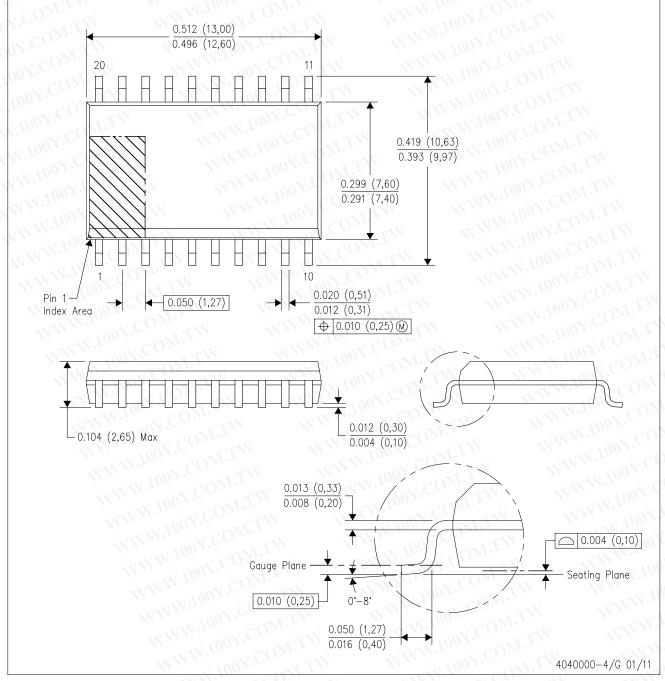
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DW (R-PDSO-G20)

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PLASTIC SMALL OUTLINE



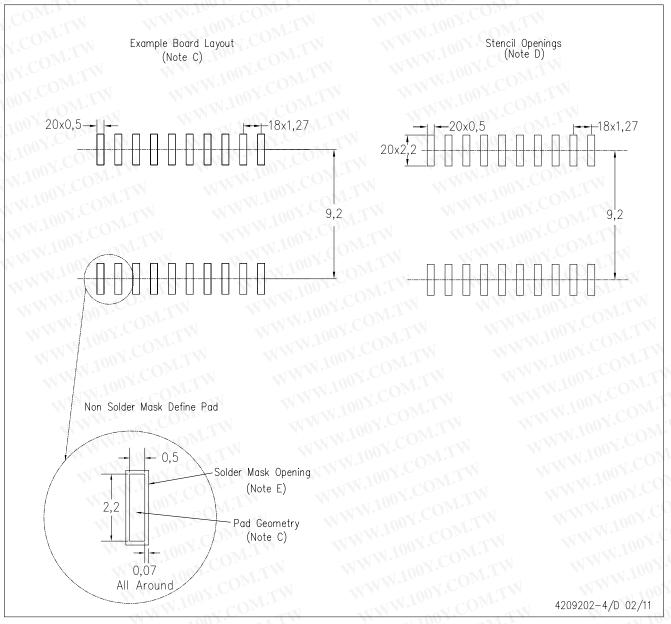
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

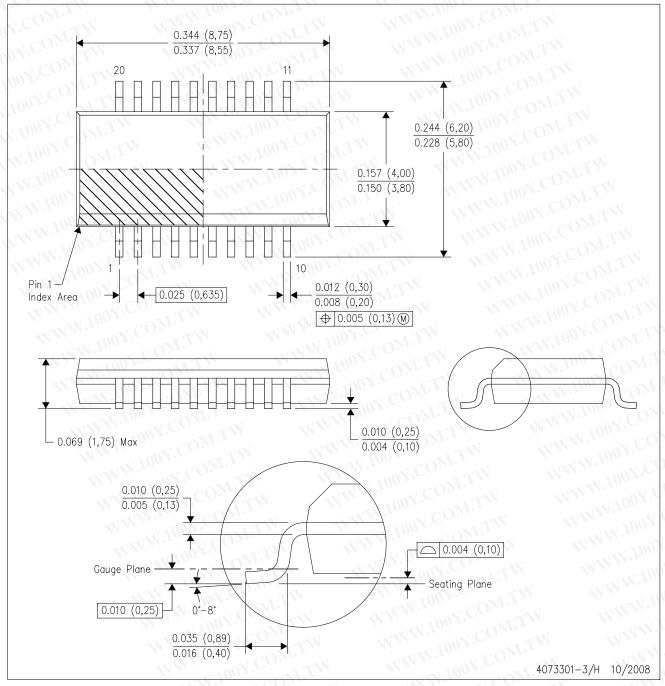
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DBQ (R-PDSO-G20)

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PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

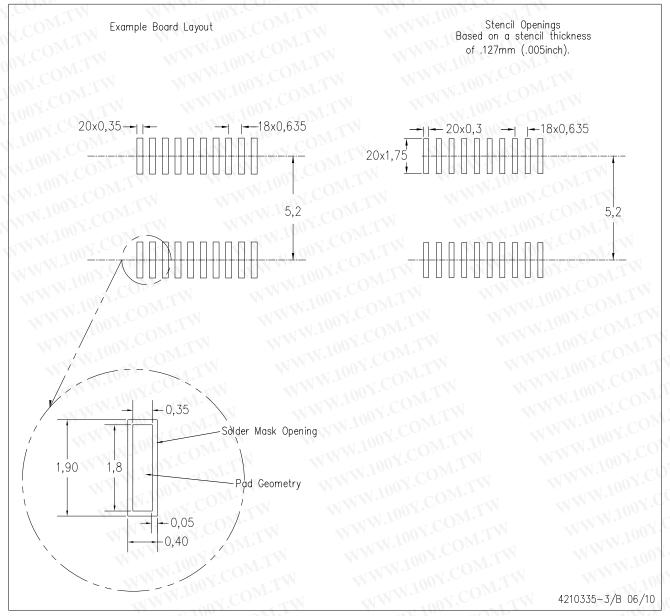
- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.
- D. Falls within JEDEC MO-137 variation AD.



DBQ (R-PDSO-G20)

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PLASTIC SMALL OUTLINE PACKAGE



NOTES:

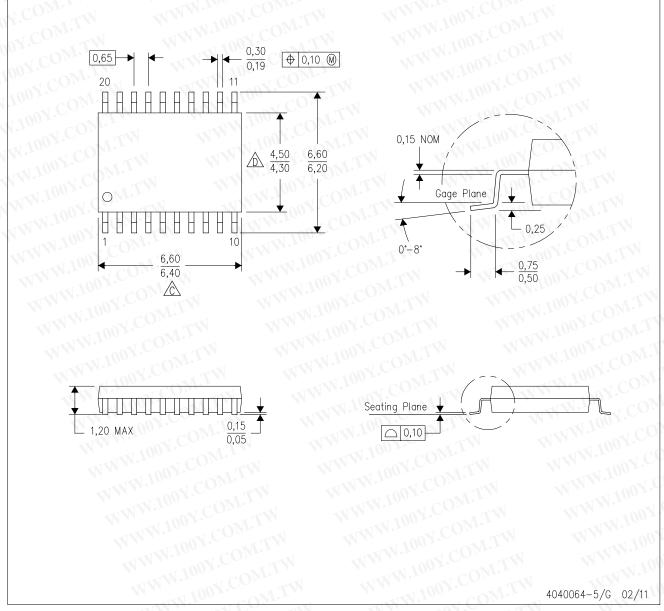
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



PW (R-PDSO-G20)

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PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
- B. This drawing is subject to change without notice.
 - Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



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